

# MOS FIELD EFFECT TRANSISTOR **2SK1580**

# N-CHANNEL MOS FET FOR SWITCHING

#### **DESCRIPTION**

The 2SK1580 is an N -channel vertical type MOS FET which can be driven by 2.5 V power supply.

As the MOS FET is driven by low voltage and does not require consideration of driving current, it is suitable for appliance including VCR cameras and headphone stereos which need power saving.

#### **FEATURES**

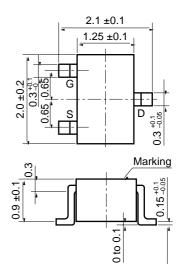
- Directly driven by ICs having a 3 V power supply.
- Not necessary to consider driving current because of its high input impedance.
- Possible to reduce the number of parts by omitting the bias resistor.

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

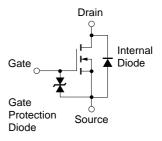
Drain to Source Voltage (Vss = 0 V)	VDSS	16	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±16	V
Drain Current (DC) (Tc = 25°C)	I <sub>D(DC)</sub>	±100	mΑ
Drain Current (pulse) Note1	D(pulse)	±200	mΑ
Total Power Dissipation (T <sub>A</sub> = 25°C)	PT	150	mW
Channel Temperature	Tch	150	°C
Operating Temperature	$T_{opt}$	-55 to +80	°C
Storage Temperature	Tstg	-55 to +150	°C

**Note1.** PW  $\leq$  10 ms, Duty Cycle  $\leq$  50%

#### PACKAGE DRAWING (Unit: mm)



#### **EQUIVALENT CIRCUIT**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

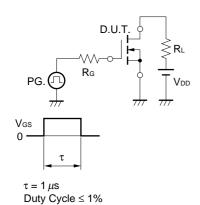
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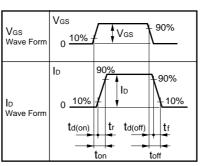


### **★** ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Ipss	V <sub>DS</sub> = 16 V, V <sub>GS</sub> = 0 V			1.0	μΑ
Gate Leakage Current	Igss	Vgs = ±3.0 V, Vps = 0 V			±5.0	nA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	$V_{DS} = 3 \text{ V}, I_{D} = 10 \mu \text{A}$	0.8	1.1	1.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> = 3 V, I <sub>D</sub> = 10 mA	20	44		mS
Drain to Source On-state Resistance	RDS(on)1	Vgs = 2.5 V, lp = 1 mA		9	15	Ω
	RDS(on)2	Vgs = 4.0 V, lp = 1 mA		6	10	Ω
Input Capacitance	Ciss	Vps = 3 V		18		pF
Output Capacitance	Coss	V <sub>G</sub> S = 0 V		22		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		4		pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = 3 V, I <sub>D</sub> = 10 mA		27		ns
Rise Time	tr	V <sub>G</sub> S = 3 V		75		ns
Turn-off Delay Time	td(off)	R <sub>G</sub> = 10 Ω		78		ns
Fall Time	t <sub>f</sub>	R <sub>L</sub> = 300 Ω		80		ns

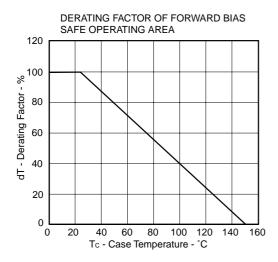
#### TEST CIRCUIT SWITCHING TIME

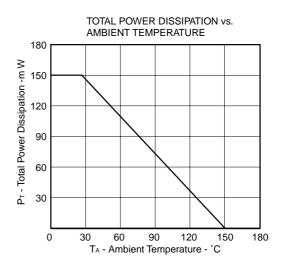


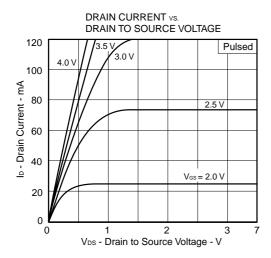


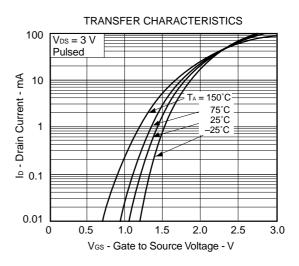
## NEC

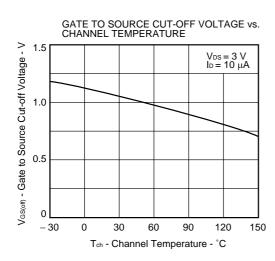
#### TYPICAL CHARACTERISTICS (TA = 25°C)

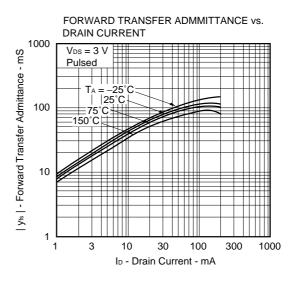




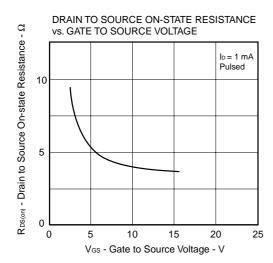


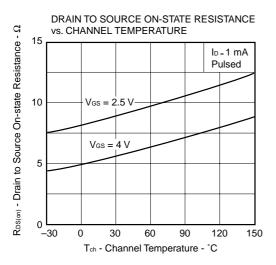


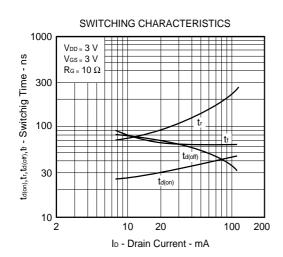


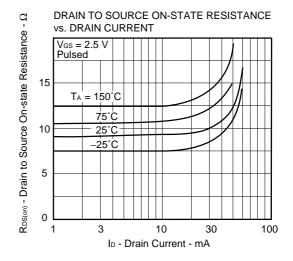


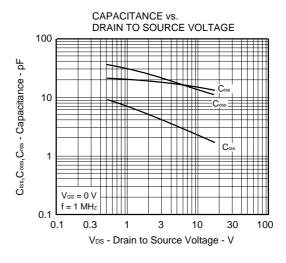
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